NSN 5961-00-813-6710

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View Online at https://aerobasegroup.com/nsn/5961-00-813-6710 **Inclosure Material:** Metal **Overall Length:** Between 0.210 inches and 0.225 inches **Terminal Length:** 1.500 inches **Overall Diameter:** Between 0.180 inches and 0.195 inches **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -30.0 collector to base voltage, dc and -1.0 emitter to base voltage, instantaneous **Current Rating Per Characteristic:** -40.00 milliamperes source cutoff current and 40.00 milliamperes source cutoff current blank **Power Rating Per Characteristic:** 150.0 milliwatts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/161 government specification Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

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